

MiniSKiiP<sup>®</sup>1

### 3-phase bridge inverter

#### SKiiP 12AC12T4V1

#### **Features**

- Trench 4 IGBT's
- · Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

#### **Typical Applications\***

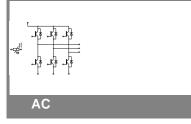
- Inverter up to 12 kVA
- Typical motor power 5,5 kW

#### Remarks

- V<sub>CEsat</sub>, V<sub>F</sub>= chip level value
  Case temp. limited to T<sub>C</sub> = 125°C max. (for baseplateless modules  $T_{C} = T_{S}$ ) • product rel. results valid for
- T<sub>j</sub>≤150 (recomm. T<sub>op</sub> = -40 ... +150°C)

Absolute Maximum Ratings T <sub>c</sub> = 25 °C, unless otherwise specifie					
Symbol	Conditions		Values	Units	
IGBT				_	
V <sub>CES</sub>	T <sub>j</sub> = 25 °C		1200	V	
I <sub>C</sub>	T <sub>j</sub> = 175 °C	T <sub>c</sub> = 25 °C	18	А	
		T <sub>c</sub> = 70 °C	18	А	
I <sub>CRM</sub>	I <sub>CRM</sub> = 3xI <sub>Cnom</sub>		45	А	
$V_{GES}$			±20	V	
t <sub>psc</sub>	$V_{CC}$ = 800 V; $V_{GE} \le 15$ V; VCES < 1200 V	T <sub>j</sub> = 150 °C	10	μs	
Inverse I	Diode				
I <sub>F</sub>	T <sub>j</sub> = 175 °C	T <sub>c</sub> = 25 °C	22	A	
		T <sub>c</sub> = 70 °C	18	А	
I <sub>FRM</sub>	I <sub>CRM</sub> = 3xI <sub>Cnom</sub>		45	А	
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms; sin.	T <sub>j</sub> = 25 °C	64	А	
Module					
I <sub>t(RMS)</sub>			40	А	
Τ <sub>νj</sub>			-40+175	°C	
T <sub>stg</sub>			-40+125	°C	
V <sub>isol</sub>	AC, 1 min.		2500	V	

Characteristics T <sub>c</sub> =			25 °C, unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Units	
IGBT							
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_C = 1 \text{ mA}$		5	5,8	6,5	V	
I <sub>CES</sub>	$V_{GE}$ = 0 V, $V_{CE}$ = $V_{CES}$	T <sub>j</sub> = 25 °C			0,3	mA	
V <sub>CE0</sub>		T <sub>j</sub> = 25 °C		0,8	0,9	V	
		T <sub>j</sub> = 150 °C		0,7	0,8	V	
r <sub>CE</sub>	V <sub>GE</sub> = 15 V	T <sub>j</sub> = 25°C		70	77	mΩ	
		T <sub>j</sub> = 150°C		103	110	mΩ	
V <sub>CE(sat)</sub>	I <sub>Cnom</sub> = 15 A, V <sub>GE</sub> = 15 V	T <sub>j</sub> = 25°C <sub>chiplev.</sub>		1,85	2,05	V	
		T <sub>j</sub> = 150°C <sub>chiplev.</sub>		2,25	2,45	V	
C <sub>ies</sub>				0,9		nF	
C <sub>oes</sub>	$V_{CE}$ = 25, $V_{GE}$ = 0 V	f = 1 MHz		0,08		nF	
C <sub>res</sub>				0,055		nF	
Q <sub>G</sub>	V <sub>GE</sub> = -8 +15 V			85		nC	
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			0		Ω	
t <sub>d(on)</sub>				31		ns	
t <sub>r</sub>	R <sub>Gon</sub> = 39 Ω	V <sub>CC</sub> = 600V		30		ns	
É <sub>on</sub>	di/dt = 400 A/µs	I <sub>C</sub> = 15A		1,65		mJ	
<sup>t</sup> d(off)	R <sub>Goff</sub> = 39 Ω	T <sub>j</sub> = 150 °C		315		ns	
t <sub>f</sub>	di/dt = 200 A/µs	$V_{GE} = \pm 15V$		66		ns	
E <sub>off</sub>				1,5		mJ	
R <sub>th(j-s)</sub>	per IGBT			1,3		K/W	





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Characteristics								
Symbol	Conditions		min.	typ.	max.	Units		
Inverse Diode								
$V_F = V_{EC}$	$I_{Fnom}$ = 15 A; $V_{GE}$ = 0 V			2,4	2,75	V		
		T <sub>j</sub> = 150 °C <sub>chiplev.</sub>		2,45	2,8	V		
V <sub>F0</sub>		T <sub>j</sub> = 25 °C		1,3	1,5	V		
		T <sub>j</sub> = 150 °C		0,9	1,1	V		
r <sub>F</sub>		T <sub>j</sub> = 25 °C		73	83	mΩ		
		T <sub>j</sub> = 150 °C		103	113	mΩ		
I <sub>RRM</sub>	I <sub>F</sub> = 15 A	T <sub>j</sub> = 150 °C		12		Α		
Q <sub>rr</sub>	di/dt = 500 A/µs	-		2		μC		
E <sub>rr</sub>	$V_{GE} = \pm 15V$			0,79		mJ		
R <sub>th(j-s)</sub>	per diode			1,92		K/W		
M <sub>s</sub>	to heat sink		2		2,5	Nm		
w				35		g		
Temperature sensor								
R <sub>ts</sub>	3%, Tr=25°C			1000		Ω		
R <sub>ts</sub>	3%, Tr=100°C			1670		Ω		

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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

